Translator, 3.3 V, 2.5 Gb/s Dual AnyLevel & trade; to LVDS Receiver/Driver/Buffer, with Internal Termination

NB4N527S is a clock or data Receiver/Driver/Buffer/Translator capable of translating AnyLevelTM input signal (LVPECL, CML, HSTL, LVDS, or LVTTL/LVCMOS) to LVDS. Depending on the distance, noise immunity of the system design, and transmission line media, this device will receive, drive or translate data or clock signals up to 2.5 Gb/s or 1.5 GHz, respectively.

The NB4N527S has a wide input common mode range of GND + 50 mV to V_{CC} – 50 mV combined with two 50 Ω internal termination resistors is ideal for translating differential or single-ended data or clock signals to 350 mV typical LVDS output levels without use of any additional external components (Figure 6).

The device is offered in a small 3 mm x 3 mm QFN-16 package. NB4N527S is targeted for data, wireless and telecom applications as well as high speed logic interface where jitter and package size are main requirements. Application notes, models, and support documentation are available on www.onsemi.com.

- Maximum Input Clock Frequency up to 1.5 GHz
- Maximum Input Data Rate up to 2.5 Gb/s (Figure 5)
- 470 ps Maximum Propagation Delay\
- 1 ps Maximum RMS Jitter
- 140 ps Maximum Rise/Fall Times
- Single Power Supply; $V_{CC} = 3.3 \text{ V} \pm 10\%$
- Temperature Compensated TIA/EIA-644 Compliant LVDS Outputs
- Internal 50 Ω Termination Resistor per Input Pin
- $\bullet~$ GND + 50 mV to V_{CC} 50 mV V_{CMR} Range
- These are Pb-Free Devices

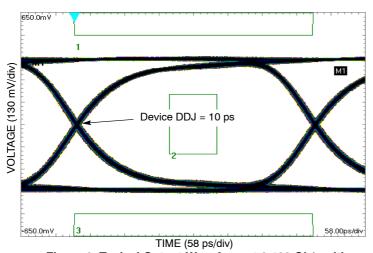


Figure 2. Typical Output Waveform at 2.488 Gb/s with PRBS 2^{23-1} (V_{INPP} = 400 mV; Input Signal DDJ = 14 ps)



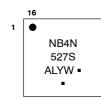
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MARKING DIAGRAM*



QFN-16 MN SUFFIX CASE 485G



A = Assembly Location

L = Wafer Lot
Y = Year
W = Work Week
■ = Pb-Free Package

(Note: Microdot may be in either location)

*For additional marking information, refer to Application Note AND8002/D.

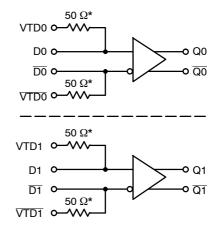


Figure 1. Functional Block Diagram

*R_{TIN}

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

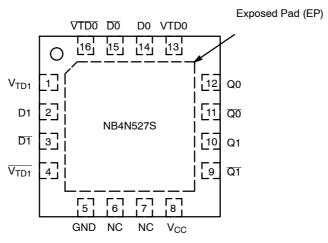


Figure 3. Pin Configuration (Top View)

Table 1. PIN DESCRIPTION

Pin	Name	I/O	Description	
1	VTD1	=	Internal 50 Ω termination pin for D1. (R _{TIN})	
2	D1	LVPECL, CML, LVDS, LVCMOS, LVTTL, HSTL	Noninverted differential clock/data D1 input (Note 1).	
3	D1	LVPECL, CML, LVDS, LVCMOS, LVTTL, HSTL	Inverted differential clock/data $\overline{D1}$ input (Note 1).	
4	VTD1	-	Internal 50 Ω termination pin for $\overline{\text{D1}}$. (R _{TIN})	
5	GND	-	0 V. Ground.	
6, 7	NC		No connect.	
8	V _{CC}		Positive Supply Voltage.	
9	Q1	LVDS Output	Inverted D1 output. Typically loaded with 100 Ω receiver termination resistor across differential pair.	
10	Q1	LVDS Output	Noninverted D1 output. Typically loaded with 100 Ω receiver termination resistor across differential pair.	
11	Q0	LVDS Output	Inverted D0 output. Typically loaded with 100 Ω receiver termination resistor across differential pair.	
12	Q0	LVDS Output	Noninverted D0 output. Typically loaded with 100 Ω receiver termination resistor across differential pair.	
13	VTD0	=	Internal 50 Ω termination pin for D0.	
14	D0	LVPECL, CML, LVDS, LVCMOS, LVTTL, HSTL	Noninverted differential clock/data D0 input (Note 1).	
15	D0	LVPECL, CML, LVDS, LVCMOS, LVTTL, HSTL	Inverted differential clock/data $\overline{D0}$ input (Note 1).	
16	VTD0	=	Internal 50 Ω termination pin for $\overline{\text{D0}}$.	
EP			Exposed pad. EP on the package bottom is thermally connected to the die improved heat transfer out of package. The pad is not electrically connected to the die, but is recommended to be soldered to GND on the PCB.	

^{1.} In the differential configuration when the input termination pins(VTD0/VTD0, VTD1/ VTD1) are connected to a common termination voltage or left open, and if no signal is applied on D0/D0, D1/D1 input, then the device will be susceptible to self–oscillation.

Table 2. ATTRIBUTES

Charac	Value		
Moisture Sensitivity (Note 2)		Level 1	
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
ESD Protection	Human Body Model Machine Model Charged Device Model	> 2 kV > 200 V > 1 kV	
Transistor Count	281		
Meets or exceeds JEDEC Spe			

^{2.} For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	Positive Power Supply	GND = 0 V		3.8	V
VI	Positive Input	GND = 0 V	V _I = V _{CC}	3.8	V
I _{IN}	Input Current Through R _T (50 Ω Resistor)	Static Surge		35 70	mA mA
I _{OSC}	Output Short Circuit Current Line-to-Line (Q to Q) Line-to-End (Q or Q to GND)	Q or $\overline{\mathbb{Q}}$ to GND Q to $\overline{\mathbb{Q}}$	Continuous Continuous	12 24	mA
T _A	Operating Temperature Range	QFN-16		-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θЈΑ	Thermal Resistance (Junction-to-Ambient) (Note 3)	0 lfpm 500 lfpm	QFN-16 QFN-16	41.6 35.2	°C/W °C/W
θ _{JC}	Thermal Resistance (Junction-to-Case)	1S2P (Note 3)	QFN-16	4.0	°C/W
T _{sol}	Wave Solder Pb Pb-Free			265 265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

^{3.} JEDEC standard multilayer board – 1S2P (1 signal, 2 power) with 8 filled thermal vias under exposed pad.

Table 4. DC CHARACTERISTICS, CLOCK INPUTS, LVDS OUTPUTS $V_{CC} = 3.0 \text{ V}$ to 3.6 V, GND = 0 V, $T_A = -40 ^{\circ}\text{C}$ to $+85 ^{\circ}\text{C}$

Symbol	Characteristic	Min	Тур	Max	Unit	
I _{CC}	Power Supply Current (Note 8)		40	53	mA	
DIFFERENTIAL INPUTS DRIVEN SINGLE-ENDED (Figures 11, 12, 16, and 18)						
V _{th}	Input Threshold Reference Voltage Range (Note 7)	GND +100		V _{CC} - 100	mV	
V _{IH}	Single-ended Input HIGH Voltage	V _{th} + 100		V _{CC}	mV	
V _{IL}	Single-ended Input LOW Voltage	GND		V _{th} – 100	mV	
DIFFERE	NTIAL INPUTS DRIVEN DIFFERENTIALLY (Figures 7, 8, 9, 10, 17, and 19)					
V_{IHD}	Differential Input HIGH Voltage	100		V _{CC}	mV	
V_{ILD}	Differential Input LOW Voltage	GND		V _{CC} - 100	mV	
V_{CMR}	Input Common Mode Range (Differential Configuration)	GND + 50		V _{CC} - 50	mV	
V_{ID}	Differential Input Voltage (V _{IHD} – V _{ILD})	100		V _{CC}	mV	
R _{TIN}	Internal Input Termination Resistor	40	50	60	Ω	
LVDS OL	ITPUTS (Note 4)					
V _{OD}	Differential Output Voltage	250		450	mV	
ΔV_{OD}	Change in Magnitude of V _{OD} for Complementary Output States (Note 9)	0	1	25	mV	
Vos	Offset Voltage (Figure 15)	1125		1375	mV	
ΔV_{OS}	Change in Magnitude of V _{OS} for Complementary Output States (Note 9)	0	1	25	mV	
V _{OH}	Output HIGH Voltage (Note 5)		1425	1600	mV	
V _{OL}	Output LOW Voltage (Note 6)	900	1075		mV	

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 4. LVDS outputs require 100 Ω receiver termination resistor between differential pair. See Figure 14.

- 5. V_{OH}max = V_{OS}max + ½ V_{OD}max.
 6. V_{OL}max = V_{OS}min ½ V_{OD}max.
 7. V_{th} is applied to the complementary input when operating in single-ended mode.
- 8. Input termination pins open, Dx/Dx at the DC level within V_{CMR} and output pins loaded with $R_L = 100 \Omega$ across differential. 9. Parameter guaranteed by design verification not tested in production.

Table 5. AC CHARACTERISTICS $V_{CC} = 3.0 \text{ V}$ to 3.6 V, GND = 0 V; (Note 10)

	-40°C		25°C			85°C					
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V _{OUTPP}	Output Voltage Amplitude (@ $V_{INPPmin}$) $f_{in} \le 1.0 \; GHz$ (Figure 4) $f_{in} = 1.5 \; GHz$	220 200	350 300		220 200	350 300		220 200	350 300		mV
f _{DATA}	Maximum Operating Data Rate	1.5	2.5		1.5	2.5		1.5	2.5		Gb/s
t _{PLH} , t _{PHL}	Differential Input to Differential Output Propagation Delay	270	370	470	270	370	470	270	370	470	ps
t _{SKEW}	Duty Cycle Skew (Note 11) Within Device Skew (Note 17) Device-to-Device Skew (Note 15)		8 5 30	45 25 100		8 5 30	45 25 100		8 5 30	45 25 100	ps
UITTER	RMS Random Clock Jitter (Note 13) $ \begin{aligned} & f_{\text{in}} = 1.0 \text{ GHz} \\ & f_{\text{in}} = 1.5 \text{ GHz} \\ & \text{Deterministic Jitter (Note 14)} \end{aligned} $ $ \begin{aligned} & f_{\text{DATA}} = 622 \text{ Mb/s} \\ & f_{\text{DATA}} = 622 \text{ Mb/s} \\ & f_{\text{DATA}} = 1.5 \text{ Gb/s} \\ & f_{\text{DATA}} = 2.488 \text{ Gb/s} \end{aligned} $ $ \end{aligned} $ $ Crosstalk Induced Jitter (Note 16) $		0.5 0.5 6 7 10 20	1 1 20 20 25 40		0.5 0.5 6 7 10 20	1 1 20 20 25 40		0.5 0.5 6 7 10 20	1 1 20 20 25 40	ps
V _{INPP}	Input Voltage Swing/Sensitivity (Differential Configuration) (Note 12)	100		V _{CC} - GND	100		V _{CC} - GND	100		V _{CC} - GND	mV
t _r t _f	Output Rise/Fall Times @ 250 MHz Q, Q (20% – 80%)	60	100	140	60	100	140	60	100	140	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 11. See Figure 13 differential measurement of t_{skew} = |t_{PLH} t_{PHL}| for a nominal 50% differential clock input waveform @ 250 MHz.
- 12. Input voltage swing is a single-ended measurement operating in differential mode.
- 13. RMS jitter with 50% duty cycle input clock signal.
- 14. Deterministic jitter with input NRZ data at PRBS 2²³-1 and K28.5.
- 15. Skew is measured between outputs under identical transition @ 250 MHz.
- 16. Crosstalk induced jitter is the additive deterministic jitter to channel one with channel two active both running at 622 Gb/s PRBS 2²³ –1 as an asynchronous signals.
- 17. The worst case condition between Q0/Q0 and Q1/Q1 from either D0/D0 or D1/D1, when both outputs have the same transition.

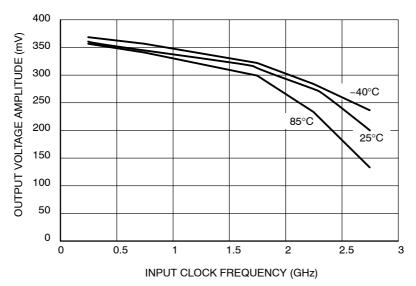


Figure 4. Output Voltage Amplitude (V_{OUTPP}) versus Input Clock Frequency (f_{in}) and Temperature (@ V_{CC} = 3.3 V)

^{10.} Measured by forcing $V_{INPPmin}$ with 50% duty cycle clock source and V_{CC} – 1400 mV offset. All loading with an external R_L = 100 Ω across "D" and " \overline{D} " of the receiver. Input edge rates 150 ps (20%–80%).

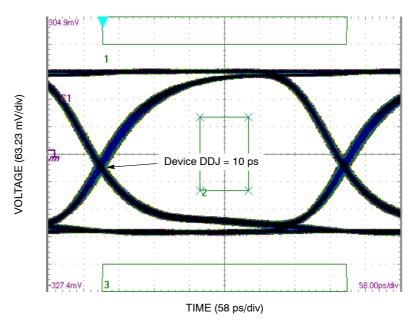


Figure 5. Typical Output Waveform at 2.488 Gb/s with PRBS 2^{23-1} and OC48 mask ($V_{INPP} = 100$ mV; Input Signal DDJ = 14 ps)

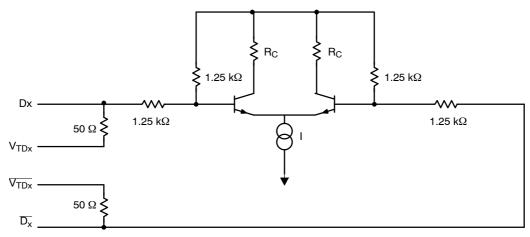


Figure 6. Input Structure

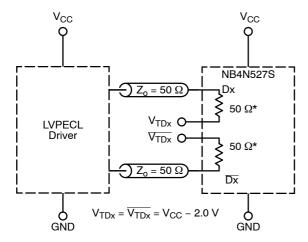


Figure 7. LVPECL Interface

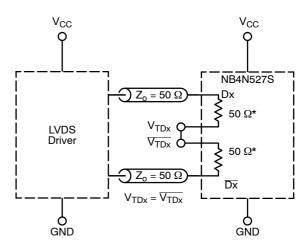


Figure 8. LVDS Interface

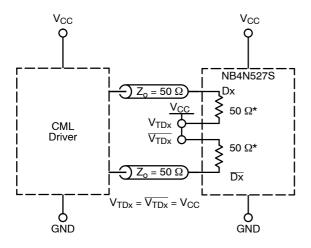


Figure 9. Standard 50 Ω Load CML Interface

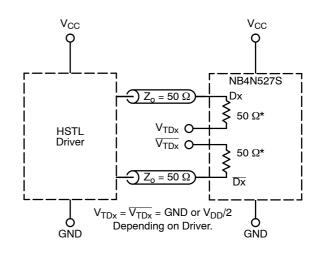


Figure 10. HSTL Interface

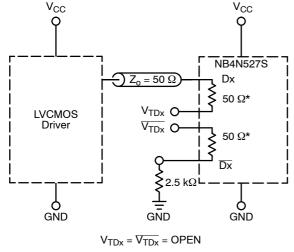


Figure 11. LVCMOS Interface

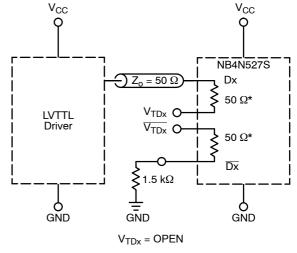


Figure 12. LVTTL Interface

*R_{TIN}, Internal Input Termination Resistor.

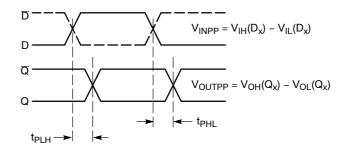


Figure 13. AC Reference Measurement

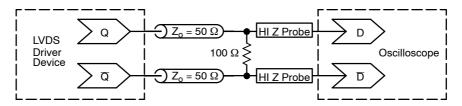


Figure 14. Typical LVDS Termination for Output Driver and Device Evaluation

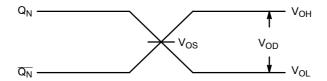


Figure 15. LVDS Output

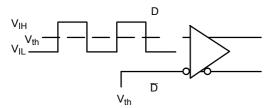


Figure 16. Differential Input Driven Single-Ended

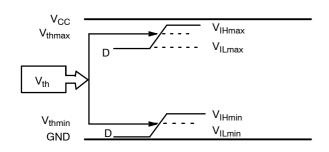


Figure 18. V_{th} Diagram

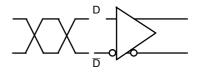


Figure 17. Differential Inputs Driven Differentially

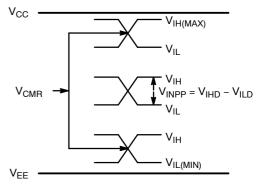


Figure 19. V_{CMR} Diagram

ORDERING INFORMATION

Device	Package	Shipping [†]
NB4N527SMNG	QFN-16 (Pb-Free)	123 Units / Rail
NB4N527SMNR2G	QFN-16 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

回

TOP VIEW

┅┅

SIDE VIEW

DETAIL B

LEA

A1

PIN ONE

LOCATION

2X 0.10 C

2X 0.10 C

// 0.05 C

□ 0.05 C

NOTE 4





Α

В

SEATING PLANE

C

Ē

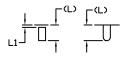
DATE 08 OCT 2021

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- DIMENSION 6 APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM THE TERMINAL TIP.
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS.
 THE TERMINALS.



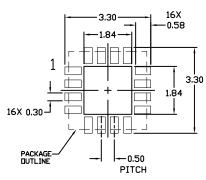
DETAIL B
ALTERNATE
CONSTRUCTIONS

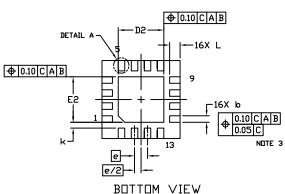


DETAIL A
ALTERNATE TERMINAL
CONSTRUCTIONS

	MILLIME				
DIM	MIN.	N□M.	MAX.		
Α	0.80	0.90	1.00		
A1	0.00	0.03	0.05		
A3		0.20 REF			
b	0.18	0.30			
D	3.00 B2C				
DS	1.65	1.85			
Ε	3.00 BSC				
E2	1.65	1.85			
e	0.50 BSC				
k	0.18 TYP				
L	0.30	0.50			
L1	0.00	0.15			

MOUNTING FOOTPRINT





GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code A = Assembly Location

L = Wafer Lot
Y = Year
W = Work Week
■ Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98AON04795D	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED"	
DESCRIPTION:	QFN16 3X3, 0.5P		PAGE 1 OF 1

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